50 V, 100 mA PNP/PNP Resistor-Equipped double Transistors (RET)

14 September 2018

Product data sheet

1. General description

PNP/PNP Resistor-Equipped double Transistors (RET) in an ultra small DFN1412-6 (SOT1268) leadless Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: PRMH11. NPN/PNP complement: PRMD3.

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- · Simplifies circuit design
- · Reduces component count
- · Reduces pick and place costs
- Low package height of 0.5 mm
- AEC-Q101 qualified

3. Applications

- · Digital applications
- · Cost-saving alternative to BC847/BC857 series in digital applications
- Control of IC inputs
- Switching loads

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	er transistor						
V _{CEO}	collector-emitter voltage	open base		-	-	-50	V
Io	output current			-	-	-100	mA
h _{FE}	DC current gain	V_{CE} = -5 V; I_{C} = -5 mA; T_{amb} = 25 °C		30	-	-	
R1	bias resistor 1	T _{amb} = 25 °C	[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	8.0	1	1.2	

[1] See section "Test information" for resistor calculation and test conditions.



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		6 5 4
2	I1	input (base) TR1	1 7 6	
3	O2	output (collector) TR2	2 5	R1 R2
4	GND2	GND (emitter) TR2		TR2
5	12	input (base) TR2	3 8 4	
6	O1	output (collector) TR1		
7	O1	output (collector) TR1	Transparent top view	1 2 3
8	O2	output (collector) TR2	DFN1412-6 (SOT1268)	006aaa212

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PRMB11	DFN1412-6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals; body: 1.4 mm x 1.2 mm x 0.47 mm	SOT1268			

7. Marking

Table 4. Marking codes

Type number	Marking code
PRMB11	C5

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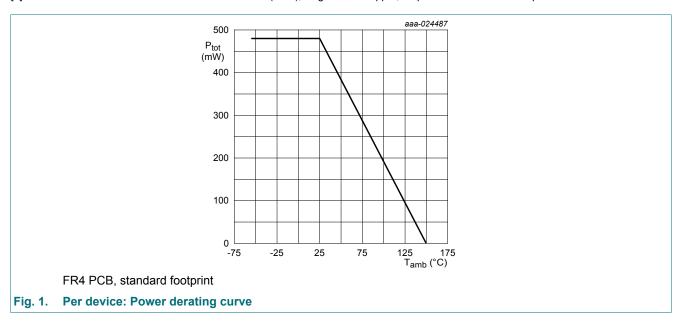
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or					
V _{CBO}	collector-base voltage	open emitter		-	-50	V
V _{CEO}	collector-emitter voltage	open base		-	-50	V
V _{EBO}	emitter-base voltage	open collector		-	-10	V
VI	input voltage	positive		-	10	V
		negative		-	-40	V
Io	output current			-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	325	mW
Per device						
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	480	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	385	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	261	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

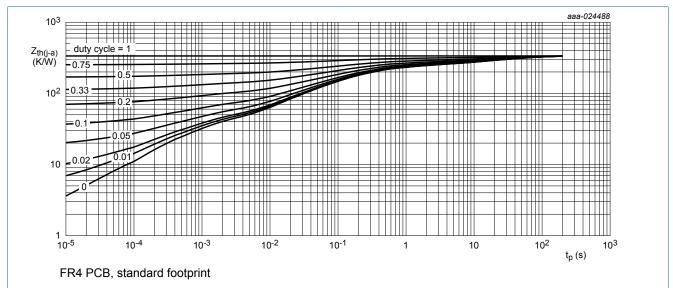


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

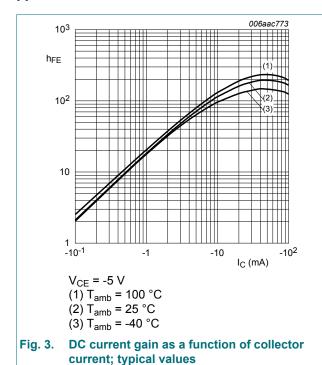
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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						<u>'</u>
I _{CEO}	collector-emitter cut-off	V _{CE} = -30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	-100	nA
	current	V _{CE} = -30 V; I _B = 0 A; T _j = 150 °C		-	-	-5	μA
I _{CBO}	collector-base cut-off current	V _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-400	μA
h _{FE}	DC current gain	V_{CE} = -5 V; I_{C} = -5 mA; T_{amb} = 25 °C		30	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = -10 mA; I_B = -0.5 mA; T_{amb} = 25 °C		-	-	-150	mV
V _{I(off)}	off-state input voltage	V_{CE} = -5 V; I_{C} = -100 μ A; T_{amb} = 25 °C		-	-1.1	-0.8	V
V _{I(on)}	on-state input voltage	V_{CE} = -0.3 V; I_{C} = -10 mA; T_{amb} = 25 °C		-2.5	-1.8	-	V
R1	bias resistor 1	T _{amb} = 25 °C	[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	
C _C	collector capacitance	V_{CB} = -10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	3	pF
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -10 mA; f = 100 MHz; T_{amb} = 25 °C	[2]	-	180	-	MHz

- [1] See section "Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor



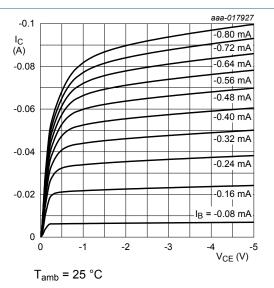
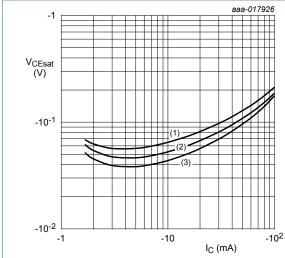


Fig. 4. Collector current as a function of collectoremitter voltage; typical values

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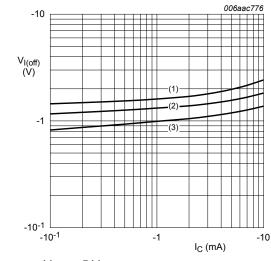


$$I_{\rm C}/I_{\rm B} = 20$$

$$(1) T_{amb} = 100 ° ($$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

Fig. 5. Collector-emitter saturation voltage as a function of collector current; typical values



$$V_{CE}$$
 = -5 V

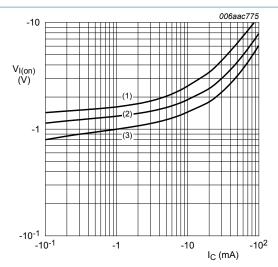
(1)
$$T_{amb} = -40 \,^{\circ}\text{C}$$

(2) $T_{amb} = 25 \,^{\circ}\text{C}$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 7. Off-state input voltage as a function of collector current; typical values

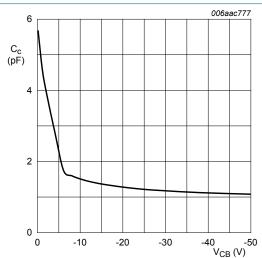


$$V_{CE} = -0.3 \text{ V}$$

$$(1) T_{amb} = -40 ° ($$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

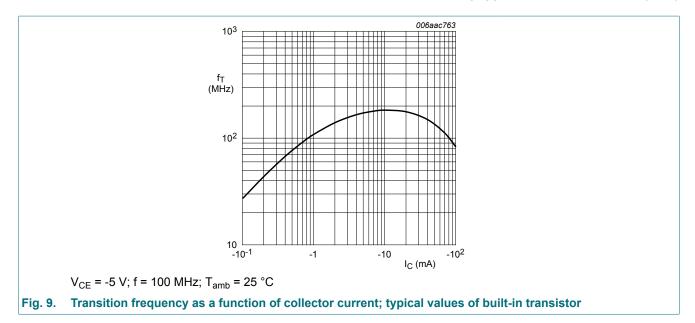
Fig. 6. On-state input voltage as a function of collector current; typical values



 $f = 1 MHz; T_{amb} = 25 °C$

Fig. 8. Collector capacitance as a function of collectorbase voltage; typical values

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11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

Resistor calculation

Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I12) - V(I11)}{I12 - I11}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$

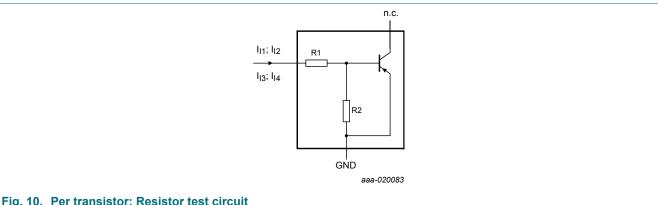


Fig. 10. Per transistor: Resistor test circuit

Resistor test conditions

Table 8. Resistor test conditions

R1 (kΩ)	R2 (kΩ)	Test conditions	est conditions				
		I _{I1}	I _{I2}	I ₁₃	I ₁₄		
10	10	-350 μΑ	-450 μA	350 μΑ	450 μΑ		

PRMB11

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12. Package outline

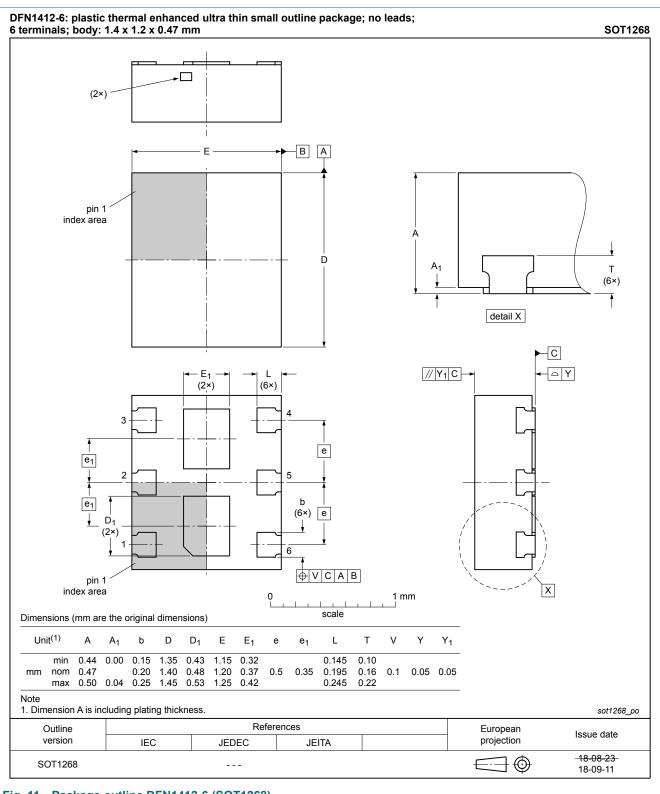
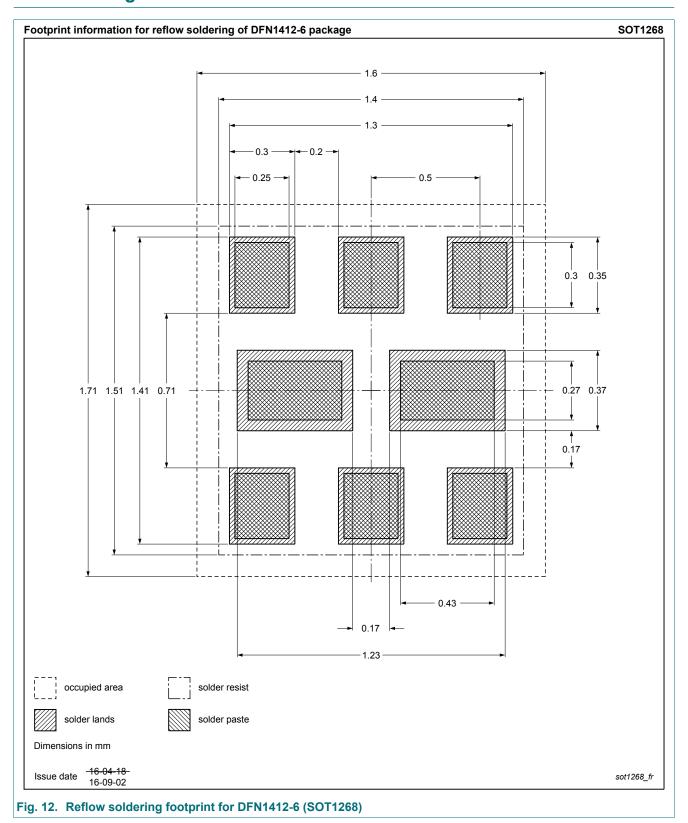


Fig. 11. Package outline DFN1412-6 (SOT1268)

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13. Soldering



DDMD44

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14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PRMB11 v.2	20180914	Product data sheet	-	PRMB11 v.1		
Modifications:	Package outline draw	Package outline drawing updated: Unit T added				
PRMB11 v.1	20170814	Product data sheet	-	-		

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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PRMB1

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